

Abstract Submitted  
for the MAR17 Meeting of  
The American Physical Society

**Electronic structure of  $\text{CuTeO}_4$  and its relationship to cuprates<sup>1</sup>**

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<sup>1</sup>This work was supported by the Center for Emergent Superconductivity, an Energy Frontier Research Center funded by the US DOE, Office of Science, under Award No. DE-AC0298CH1088

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Date submitted: 09 Nov 2016

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